Amendments to the Claims

Claims 1-10 (Cancelled).

11. (Previously presented): A boron and/or phosphorus doped silicon dioxide selective to undoped SiO₂ and Si₃N₄ etchant gas composition, consisting essentially of:

a carrier gas;

at least one of C_4F_6 and C_5F_8 ;

CH₂F₂; and

CF₄, the etchant gas composition being selective to both undoped SiO₂ and Si₃N₄ relative to doped SiO₂ comprising one or both of boron and phosphorous.

Claims 12 and 13 (Cancelled).

- 14. (Original): The etchant gas composition according to Claim 11, wherein the carrier gas is selected from the group consisting of argon, helium, and xenon.
- 15. (Previously Presented): The etchant gas composition according to Claim11, wherein the carrier gas comprises argon.

16. (Previously presented): A boron and/or phosphorus doped silicon dioxide selective to undoped SiO₂ and Si₃N₄ etchant gas composition, consisting essentially of:

a carrier gas;

at least one of C_4F_6 and C_5F_8 ;

CH₂F₂;

CHF₃; and

 CF_4 constituting a boron and/or phosphorus doped silicon dioxide selective to undoped SiO_2 and Si_3N_4 etchant gas composition.

Claims 17 and 18 (Cancelled).

- 19. (Previously presented): The etchant gas composition according to Claim 16, wherein the carrier gas is selected from the group consisting of argon, helium, and xenon.
- 20. (Previously Presented): The etchant gas composition according to Claim16, wherein the carrier gas comprises argon.

Claims 21-68. (Cancelled).

69. (Previously Presented): The etchant gas composition according to Claim
11 wherein the carrier gas comprises helium.

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70. (Previously Presented): The etchant gas composition according to Claim 16 wherein the carrier gas comprises helium.

Claims 71-72 (Cancelled).

- 73. (Previously Presented): The etchant gas composition according to Claim

 11 wherein the carrier gas comprises xenon.
- 74. (Previously Presented): The etchant gas composition according to Claim16 wherein the carrier gas comprises xenon.

Claims 75-80 (Cancelled).

81. (Currently amended): The etchant gas composition according to Claim 11, containing contains C₄F₆.

Claim 82 (Cancelled).

- 83. (Currently amended): The etchant gas composition according to Claim 11, containing centains C_5F_8 .
- 84. (Currently amended): The etchant gas composition according to Claim 16, containing contains C₄F₆.

Claim 85 (Cancelled).

86. (Currently amended):

The etchant gas composition according to Claim

16, containing contains C₅F₈.